Power MOSFET 30 V, 7.5 A, Single N–Channel, SOIC–8

Features

- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- Optimized Gate Charge to Minimize Switching Losses
- SOIC-8 Surface Mount Package Saves Board Space
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- DC-DC Converters
- Printers

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Ratir	Symbol	Value	Unit		
Drain-to-Source Voltage			V _{DSS}	30	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain Current $R_{\theta JA}$ (Note 1)		$T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$	I _D	5.5 4.4	A
Power Dissipation $R_{\theta JA}$ (Note 1)		T _A = 25°C	P _D	1.14	W
Continuous Drain		T _A = 25°C	۱ _D	4.5	Α
Current $R_{\theta JA}$ (Note 2)	Steady	T _A = 70°C		3.5	
Power Dissipation $R_{\theta JA}$ (Note 2)	State	T _A = 25°C	PD	0.68	W
Continuous Drain		T _A = 25°C	Ι _D	7.5	Α
Current R _{θJA} t < 10 s (Note 1)		T _A = 70°C		6.0	
Power Dissipation $R_{\theta JA} t < 10 s (Note 1)$		T _A = 25°C	PD	1.95	W
Pulsed Drain Current	T _A = 25°C, t _p = 10 μs		I _{DM}	38	A
Operating Junction and Storage Temperature			T _J , T _{STG}	–55 to +150	°C
Source Current (Body Diode)			I _S	2.0	Α
Single Pulse Drain-to-Source Avalanche Energy T _J = 25°C, V _{DD} = 30 V, V _{GS} = 10 V, I _L = 7.5 A _{pk} , L = 1.0 mH, R _G = 25 Ω			EAS	28	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

THERMAL RESISTANCE RATINGS

Rating	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	110	
Junction–to–Ambient – t≤10 s (Note 1)	R_{\thetaJA}	64	°C/W
Junction-to-FOOT (Drain)	$R_{\theta JF}$	40	0/11
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	183.5	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface-mounted on FR4 board using 1 inch sq pad size, 1 oz Cu.

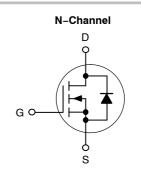
2. Surface-mounted on FR4 board using the minimum recommended pad size.



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V _{(BR)DSS}	R _{DS(on)} Max	I _D Max
30 V	24 mΩ @ 10 V	7.5 A
	36 mΩ @ 4.5 V	1.077



MARKING DIAGRAM & PIN ASSIGNMENT

Source Drain



8 751 12	Source Source Gate T	AYWW op View	 ➡ Drain ➡ Drain ➡ Drain
S4840	= Device Code		

0-0-0	
A	= Assembly Location
Y	= Year
WW	= Work Week

- = Pb-Free Package

ORDERING INFORMATION

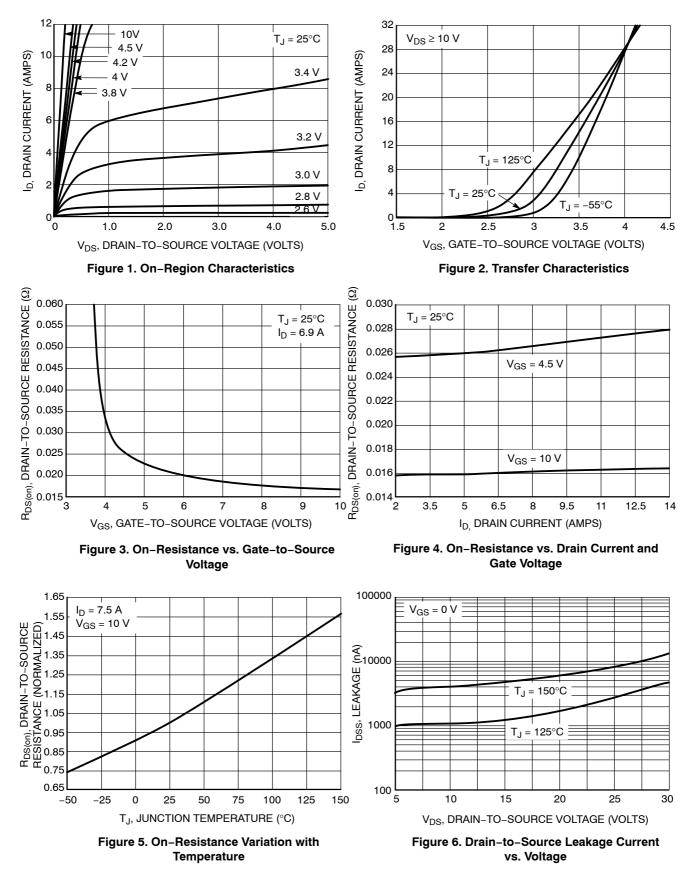
Device	Package	Shipping [†]
NTMS4840NR2G	SOIC-8 (Pb-Free)	2500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

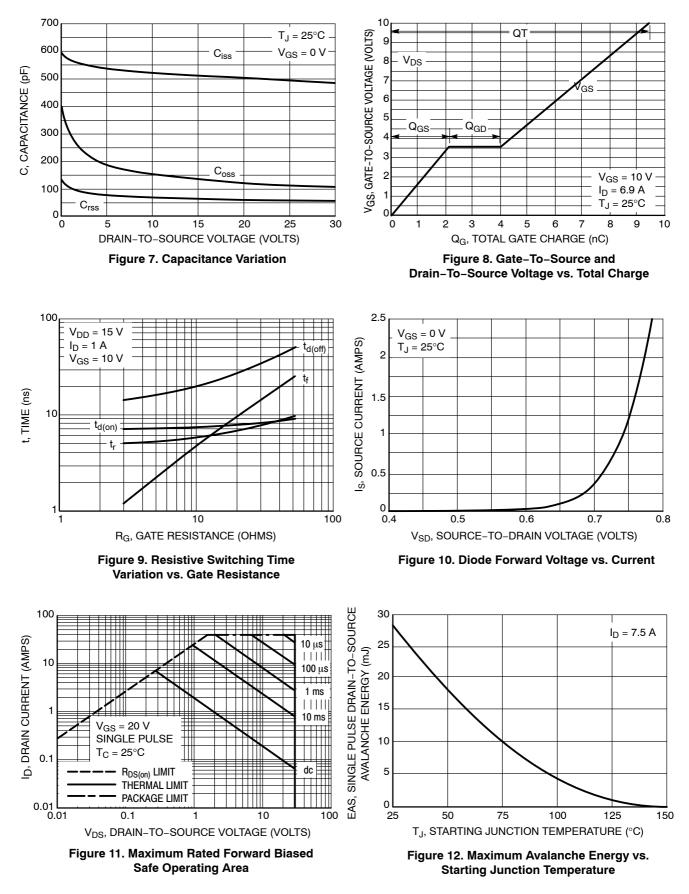
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)jk

Symbol	Test Con	dition	Min	Тур	Max	Unit
-						
V _{(BR)DSS}	$V_{GS} = 0 V, I_{D}$	o = 250 μA	30			V
V _{(BR)DSS} /T _J				18		mV/°C
I _{DSS}	V _{GS} = 0 V, V _{DS} = 24 V	T _J = 25°C T _J = 100°C			1.0 10	μΑ
I _{GSS}	V _{DS} = 0 V, V ₀	_{GS} = ±20 V			±100	nA
-1	•			<u> </u>		
V _{GS(TH)}	V _{GS} = V _{DS} , I _I	_D = 250 μA	1.5		3.0	V
V _{GS(TH)} /T _J				6.0		mV/°C
R _{DS(on)}	V _{GS} = 10 V	I _D = 6.9 A		16	24	mΩ
	V _{GS} = 4.5 V	I _D = 5.0 A		26	36	11152
9 _{FS}	V _{DS} = 1.5 V,	I _D = 6.9 A		15		S
RESISTANCE						
C _{ISS}				520		
C _{OSS}	V_{GS} = 0 V, f = 1.0 MHz, V_{DS} = 15 V			140		pF
C _{RSS}				70		
Q _{G(TOT)}				4.8		
Q _{G(TH)}	V _{GS} = 4.5 V, V _{DS} = 15 V, I _D = 6.9 A			1.1		nC
Q _{GS}				2.1		
Q _{GD}				1.9		1
Q _{G(TOT)}	V _{GS} = 10 V, V _{DS} =	15 V, I _D = 6.9 A		9.5		nC
)						
t _{d(ON)}				7.6		
t _r	V _{GS} = 10 V, V	ה = 15 V,		5.0		ns
t _{d(OFF)}	I _D = 1.0 A, R	$G = 3.0 \Omega$		17		
t _f				3.0		1
S						
V _{SD}	V _{GS} = 0 V	$T_J = 25^{\circ}C$		0.77	1.0	V
	$I_{\rm D} = 2.0 {\rm A}$	T _J = 125°C		0.58		
t _{RR}				12.5		
Ta	$V_{GS} = 0 V, d_{IS}/d_{IS}$	_t = 100 A/μs,		7.3		ns
Tb	$I_{\rm S} = 2.0 \rm{A}$			5.2		1
Q _{RR}				6.0		nC
L _S				0.66		nH
L _D		F ⁰ O		0.20		nH
+	$T_A = 25^{\circ}C$			4.50		۳Ц
L _G				1.50		nH
	V(BR)DSS V(BR)DSS/TJ IDSS IDSS IGSS VGS(TH) VGS(TH)/TJ PRDS(on) 9FS CISS CGSS CRSS QG(TOT) QG(TOT) QG(TOT) CqG QG(TOT) CqG QG(TOT) CqG QG(TOT) CqG QG QG	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

TYPICAL PERFORMANCE CURVES



TYPICAL PERFORMANCE CURVES



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*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN З. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. 8. CATHODE STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE

6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW_TO_GND 2. DASIC OFF DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK

7. VOULK 8. VIN

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SOURCE 1/DRAIN 2

7.

8. GATE 1

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7.

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COLLECTOR, #1

COLLECTOR, #1

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